



S-8215C Series

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BATTERY PROTECTION IC FOR 3-SERIAL TO 5-SERIAL CELL PACK (SECONDARY PROTECTION)

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Rev. 1.3 00

The S-8215C Series is used for secondary protection of lithium-ion rechargeable batteries, which includes high-accuracy voltage detection circuits and delay circuits.

Short-circuiting between cells makes it possible for serial connection of three cells to five cells.

■ Features

- High-accuracy voltage detection circuit for each cell
 - Overcharge detection voltage n (n = 1 to 5):
 - 2.700 V to 4.700 V (5 mV step)
 - Accuracy ± 20 mV ($T_a = +25^\circ\text{C}$)
 - Accuracy ± 25 mV ($T_a = -10^\circ\text{C}$ to $+60^\circ\text{C}$)
 - Overcharge release voltage n (n = 1 to 5)*1:
 - 2.700 V to 4.700 V
 - Accuracy ± 50 mV ($T_a = +25^\circ\text{C}$)
 - Overcharge detection delay times are generated only by an internal circuit (external capacitors are unnecessary)
 - Overcharge detection delay time: 0.5 s, 1 s, 2 s, 4 s, 6 s, 8 s
 - Output form: CMOS output, Nch open-drain output
 - Output logic: Active "H", active "L"
 - Built-in test mode function to check overcharge detection voltage with shortened delay time
 - High-withstand voltage: Absolute maximum rating 28 V
 - Wide operation voltage range: 3.6 V to 26 V
 - Wide operation temperature range: $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$
 - Low current consumption
 - During operation: 0.3 μA typ., 0.7 μA max. ($T_a = +25^\circ\text{C}$)
 - Lead-free (Sn 100%), halogen-free

*1. Overcharge release voltage = Overcharge detection voltage + Overcharge hysteresis voltage
(Overcharge hysteresis voltage can be selected from a range of 0 mV to -400 mV in 50 mV step.)

■ Application

- Lithium-ion rechargeable battery pack

■ Packages

- TMSOP-8
- SNT-8A

■ Block Diagram

1. CMOS output product

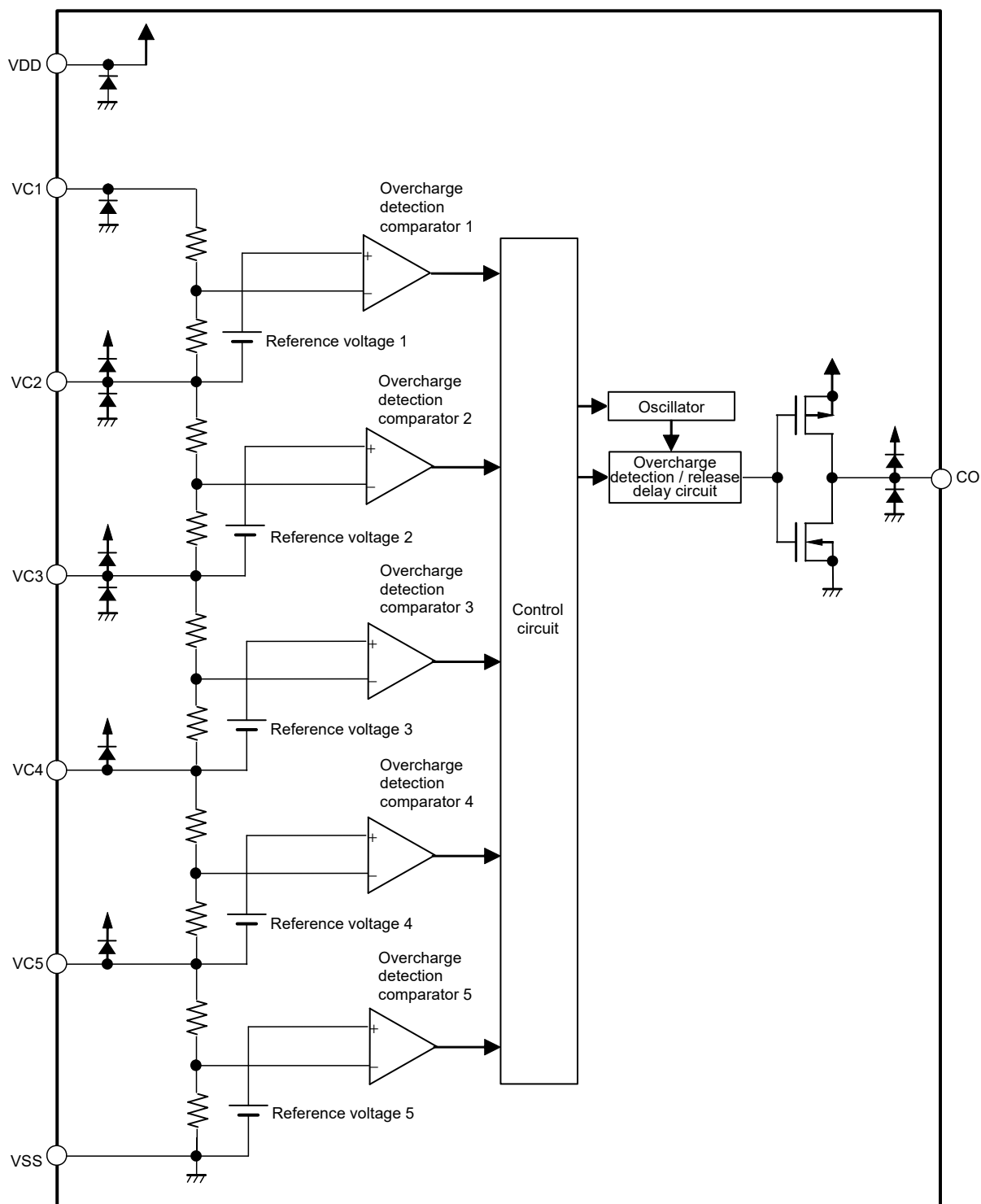


Figure 1

Remark The diodes in the figure are parasitic diodes.

2. Nch open-drain output product

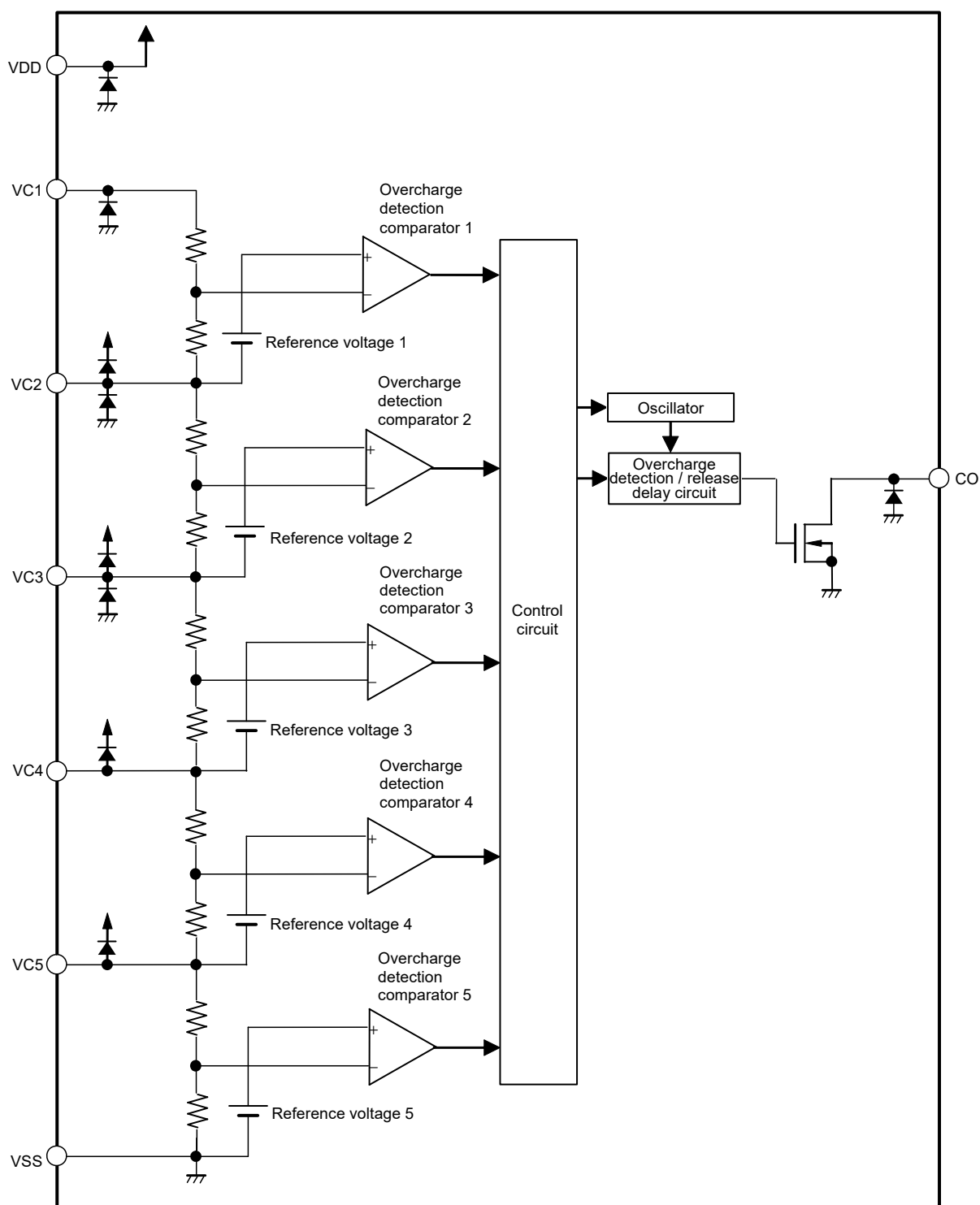
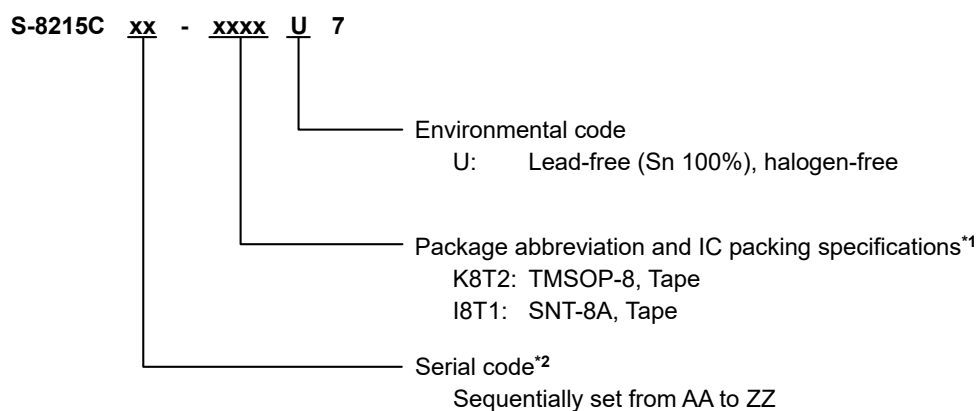


Figure 2

Remark The diodes in the figure are parasitic diodes.

■ Product Name Structure

1. Product name



*1. Refer to the tape drawing.

*2. Refer to "3. Product name list".

2. Packages

Table 1 Package Drawing Codes

| Package Name | Dimension | Tape | Reel | Land |
|--------------|--------------|--------------|--------------|--------------|
| TMSOP-8 | FM008-A-P-SD | FM008-A-C-SD | FM008-A-R-SD | — |
| SNT-8A | PH008-A-P-SD | PH008-A-C-SD | PH008-A-R-SD | PH008-A-L-SD |

3. Product name list

3.1 TMSOP-8

Table 2

| Product Name | Overcharge Detection Voltage [V _{CU}] | Overcharge Release Voltage [V _{CL}] | Overcharge Detection Delay Time [t _{CU}] | Output Form | Output Logic |
|------------------|--|--|---|-----------------------|--------------|
| S-8215CAA-K8T2U7 | 4.325 V | 4.275 V | 8 s | CMOS output | Active "H" |
| S-8215CAB-K8T2U7 | 4.325 V | 4.025 V | 8 s | CMOS output | Active "H" |
| S-8215CAC-K8T2U7 | 4.350 V | 4.100 V | 2 s | CMOS output | Active "H" |
| S-8215CAD-K8T2U7 | 4.250 V | 4.000 V | 1 s | CMOS output | Active "H" |
| S-8215CAE-K8T2U7 | 4.300 V | 4.000 V | 4 s | CMOS output | Active "H" |
| S-8215CAF-K8T2U7 | 4.275 V | 4.225 V | 2 s | Nch open-drain output | Active "L" |

Remark Please contact our sales representatives for products other than the above.

3.2 SNT-8A

Table 3

| Product Name | Overcharge Detection Voltage [V _{CU}] | Overcharge Release Voltage [V _{CL}] | Overcharge Detection Delay Time [t _{CU}] | Output Form | Output Logic |
|------------------|--|--|---|-------------|--------------|
| S-8215CAA-I8T1U7 | 4.325 V | 4.275 V | 8 s | CMOS output | Active "H" |

Remark Please contact our sales representatives for products other than the above.

■ Pin Configurations

1. TMSOP-8

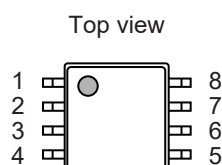


Figure 3

Table 4

| Pin No. | Symbol | Description |
|---------|--------|---|
| 1 | VDD | Input pin for positive power supply |
| 2 | VC1 | Positive voltage connection pin of battery 1 |
| 3 | VC2 | Negative voltage connection pin of battery 1, Positive voltage connection pin of battery 2 |
| 4 | VC3 | Negative voltage connection pin of battery 2, Positive voltage connection pin of battery 3 |
| 5 | VC4 | Negative voltage connection pin of battery 3, Positive voltage connection pin of battery 4 |
| 6 | VC5 | Negative voltage connection pin of battery 4, Positive voltage connection pin of battery 5 |
| 7 | VSS | Input pin for negative power supply, Negative voltage connection pin of battery 5 |
| 8 | CO | FET gate connection pin for charge control |

2. SNT-8A

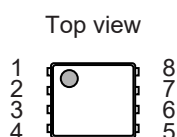


Figure 4

Table 5

| Pin No. | Symbol | Description |
|---------|--------|---|
| 1 | VDD | Input pin for positive power supply |
| 2 | VC1 | Positive voltage connection pin of battery 1 |
| 3 | VC2 | Negative voltage connection pin of battery 1, Positive voltage connection pin of battery 2 |
| 4 | VC3 | Negative voltage connection pin of battery 2, Positive voltage connection pin of battery 3 |
| 5 | VC4 | Negative voltage connection pin of battery 3, Positive voltage connection pin of battery 4 |
| 6 | VC5 | Negative voltage connection pin of battery 4, Positive voltage connection pin of battery 5 |
| 7 | VSS | Input pin for negative power supply, Negative voltage connection pin of battery 5 |
| 8 | CO | FET gate connection pin for charge control |

■ Absolute Maximum Ratings

Table 6

(Ta = +25°C unless otherwise specified)

| Item | | Symbol | Applied Pin | Absolute Maximum Rating | Unit |
|---|-------------------------------|------------------|-------------|--|------|
| Input voltage between VDD pin and VSS pin | | V _{DS} | VDD | V _{SS} – 0.3 to V _{SS} + 28 | V |
| Input pin voltage | | V _{IN} | VC1 | V _{SS} – 0.3 to V _{SS} + 28 | V |
| | | | VC2, VC3 | V _{SS} – 0.3 to V _{DD} + 0.3 | V |
| | | | VC4, VC5 | V _{DD} – 28 to V _{DD} + 0.3 | V |
| | | | | | |
| CO pin output voltage | CMOS output product | V _{CO} | CO | V _{SS} – 0.3 to V _{DD} + 0.3 | V |
| | Nch open-drain output product | | | V _{SS} – 0.3 to V _{SS} + 28 | V |
| Operation ambient temperature | | T _{opr} | – | –40 to +85 | °C |
| Storage temperature | | T _{stg} | – | –40 to +125 | °C |

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

■ Thermal Resistance Value

Table 7

| Item | Symbol | Condition | | Min. | Typ. | Max. | Unit |
|--|---------------|-----------|---------|------|------|------|------|
| Junction-to-ambient thermal resistance*1 | θ_{JA} | TMSOP-8 | Board A | – | 160 | – | °C/W |
| | | | Board B | – | 133 | – | °C/W |
| | | | Board C | – | – | – | °C/W |
| | | | Board D | – | – | – | °C/W |
| | | | Board E | – | – | – | °C/W |
| | | SNT-8A | Board A | – | 211 | – | °C/W |
| | | | Board B | – | 173 | – | °C/W |
| | | | Board C | – | – | – | °C/W |
| | | | Board D | – | – | – | °C/W |
| | | | Board E | – | – | – | °C/W |

*1. Test environment: compliance with JEDEC STANDARD JESD51-2A

Remark Refer to "■ Power Dissipation" and "Test Board" for details.

■ Electrical Characteristics

Table 8

(Ta = +25°C unless otherwise specified)

| Item | Symbol | Condition | Min. | Typ. | Max. | Unit | Test Circuit |
|---|-----------------------------|--|----------------------------|-----------------|----------------------------|------|--------------|
| Detection voltage | | | | | | | |
| Overcharge detection voltage n (n = 1, 2, 3, 4, 5) | V _{CU_n} | Ta = +25°C | V _{CU} − 0.020 | V _{CU} | V _{CU} + 0.020 | V | 1 |
| | | Ta = −10°C to +60°C*1 | V _{CU} − 0.025 | V _{CU} | V _{CU} + 0.025 | V | 1 |
| Overcharge release voltage n (n = 1, 2, 3, 4, 5) | V _{CL_n} | — | V _{CL} − 0.050 | V _{CL} | V _{CL} + 0.050 | V | 1 |
| Input voltage | | | | | | | |
| Operation voltage between VDD pin and VSS pin | V _{DSOP} | — | 3.6 | — | 26 | V | — |
| Input current | | | | | | | |
| Current consumption during operation | I _{OPE} | V1 = V2 = V3 = V4 = V5 = V _{CU} × 0.75 V | — | 0.3 | 0.7 | μA | 2 |
| Current consumption during overdischarge | I _{OPED} | V1 = V2 = V3 = V4 = V5 = V _{CU} × 0.4 V | — | 0.05 | 0.30 | μA | 2 |
| VC1 pin input current | I _{VC1} | V1 = V2 = V3 = V4 = V5 = V _{CU} × 0.75 V | — | — | 0.3 | μA | 3 |
| VCn pin input current (n = 2, 3, 4, 5) | I _{VC_n} | V1 = V2 = V3 = V4 = V5 = V _{CU} × 0.75 V | −0.3 | 0.0 | 0.3 | μA | 3 |
| Output current | | | | | | | |
| CO pin source current | I _{COH} | — | — | — | −20 | μA | 4 |
| CO pin sink current | I _{COL} | CMOS output product | 0.4 | — | — | mA | 4 |
| CO pin leakage current | I _{COLL} | Nch open-drain output product | — | — | 0.1 | μA | 4 |
| Delay time | | | | | | | |
| Overcharge detection delay time | t _{CU} | — | t _{CU} × 0.8 | t _{CU} | t _{CU} × 1.2 | s | 1 |
| Overcharge timer reset delay time | t _{TR} | — | 6 | 12 | 20 | ms | 1 |
| Transition time to test mode | t _{TST} | — | — | — | 10 | ms | 1 |

*1. Since products are not screened at high and low temperature, the specification for this temperature range is guaranteed by design, not tested in production.

■ Test Circuits

1. Overcharge detection voltage n (V_{CU_n}), overcharge release voltage n (V_{CL_n}) (Test circuit 1)

After setting $V_0 = 0\text{ V}$, V_1 to $V_5 = V_{CU} - 0.05\text{ V}$, V_1 is gradually increased. When the CO pin output inverts, the voltage V_1 is defined as V_{CU1} .

V_0 is then returned to 0 V . After setting $V_1 = V_{CU} + 0.05\text{ V}$, V_2 to $V_5 = V_{CL} - 0.05\text{ V}$, V_1 is gradually decreased. When the CO pin output inverts again, the voltage V_1 is defined as V_{CL1} .

V_{CU_n} and V_{CL_n} ($n = 2$ to 5) can be defined in the same way as when $n = 1$.

2. Output current (Test circuit 4)

2. 1 CMOS output product

SW1 and SW2 are set to OFF.

2. 1. 1 Active "H"

(1) CO pin source current (I_{COH})

After setting $V_0 = 0\text{ V}$, $V_1 = 4.8\text{ V}$, V_2 to $V_5 = 2.05\text{ V}$ and $V_6 = 0.5\text{ V}$, SW1 is turned on. I_6 is then defined as I_{COH} .

(2) CO pin sink current (I_{COL})

After setting $V_0 = 0\text{ V}$, V_1 to $V_5 = 2.6\text{ V}$ and $V_7 = 0.5\text{ V}$, SW2 is turned on. I_7 is then defined as I_{COL} .

2. 1. 2 Active "L"

(1) CO pin source current (I_{COH})

After setting $V_0 = 0\text{ V}$, V_1 to $V_5 = 2.6\text{ V}$ and $V_6 = 0.5\text{ V}$, SW1 is turned on. I_6 is then defined as I_{COH} .

(2) CO pin sink current (I_{COL})

After setting $V_0 = 0\text{ V}$, $V_1 = 4.8\text{ V}$, V_2 to $V_5 = 2.05\text{ V}$ and $V_7 = 0.5\text{ V}$, SW2 is turned on. I_7 is then defined as I_{COL} .

2. 2 Nch open-drain output product

SW1 and SW2 are set to OFF.

2. 2. 1 Active "H"

(1) CO pin leakage current "L" (I_{COLL})

After setting $V_0 = 0\text{ V}$, $V_1 = 4.8\text{ V}$, V_2 to $V_5 = 2.05\text{ V}$ and $V_7 = 28\text{ V}$, SW2 is turned on. I_7 is then defined as I_{COLL} .

(2) CO pin sink current (I_{COL})

After setting $V_0 = 0\text{ V}$, V_1 to $V_5 = 2.6\text{ V}$ and $V_7 = 0.5\text{ V}$, SW2 is turned on. I_7 is then defined as I_{COL} .

2. 2. 2 Active "L"

(1) CO pin leakage current "L" (I_{COLL})

After setting $V_0 = 0\text{ V}$, V_1 to $V_5 = 2.6\text{ V}$, $V_7 = 28\text{ V}$, SW2 is turned on. I_7 is then defined as I_{COLL} .

(2) CO pin sink current (I_{COL})

After setting $V_0 = 0\text{ V}$, $V_1 = 4.8\text{ V}$, V_2 to $V_5 = 2.05\text{ V}$ and $V_7 = 0.5\text{ V}$, SW2 is turned on. I_7 is then defined as I_{COL} .

3. Overcharge detection delay time (t_{CU})

(Test circuit 1)

After setting $V_0 = 0\text{ V}$, V_1 to $V_5 = 2.6\text{ V}$, V_1 is increased to 4.8 V . The time interval from this increase until the CO pin output inverts is t_{CU} .

4. Overcharge timer reset delay time (t_{TR})

(Test circuit 1)

After setting $V_0 = 0\text{ V}$, V_1 to $V_5 = 2.6\text{ V}$, V_1 is increased to 4.8 V (first rise) and decreased to 2.6 V (V_1 fall) within t_{CU} . After that, V_1 is increased to 4.8 V again (second rise), and measure the time interval until the CO pin output inverts. When the time interval from V_1 fall until the second rise is short, the CO pin output inverts when t_{CU} has elapsed since the first rise. However, if the time interval is gradually made longer, CO pin output inverts when t_{CU} has elapsed since the second rise. The time interval from V_1 fall until the second rise at that time is t_{TR} .

5. Transition time to test mode (t_{TST})

(Test circuit 1)

After setting $V_0 = 0\text{ V}$, V_1 to $V_5 = 2.6\text{ V}$, V_0 is increased to 4.0 V and decreased to 0 V again.

When the time interval from when V_0 is increased until it is decreased is long, if V_1 is then increased to 4.8 V , the CO pin output inverts within 40 ms . However, when the time interval from when V_0 is increased until it is decreased is short, if V_1 is then increased to 4.8 V , it takes more than 40 ms for the CO pin output to invert. t_{TST} is the minimum value of the time interval from V_0 rise until V_0 fall under the condition that the CO pin output inverts within 40 ms .

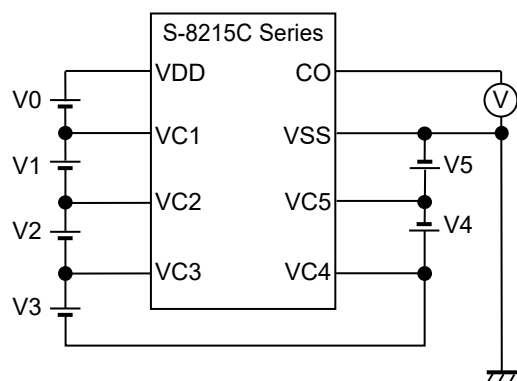


Figure 5 Test Circuit 1

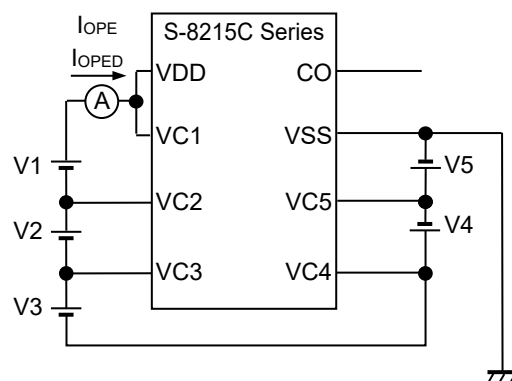


Figure 6 Test Circuit 2

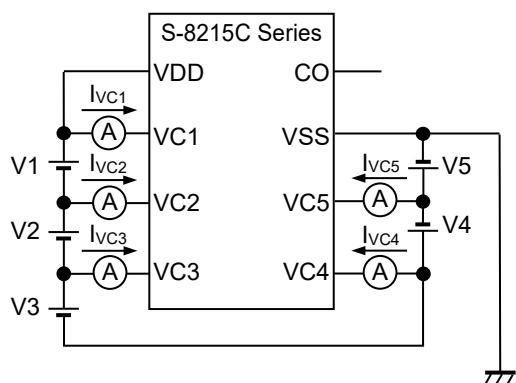


Figure 7 Test Circuit 3

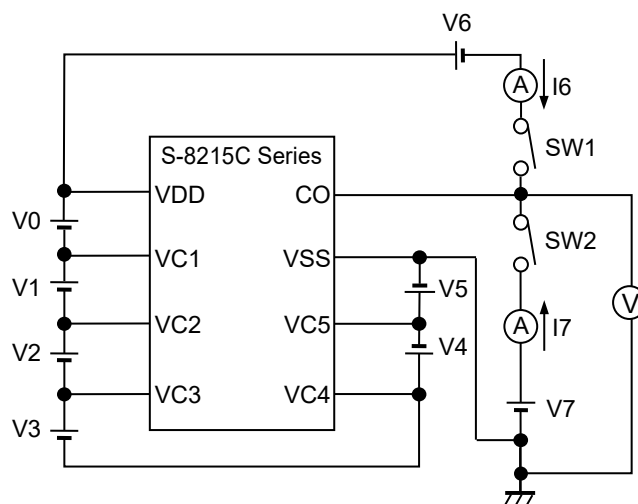


Figure 8 Test Circuit 4

■ Operation

Remark Refer to "■ Battery Protection IC Connection Examples".

1. Normal status

When the voltage of all batteries is lower than overcharge release voltage n (V_{CLn}), "L" (Active "H") or "H" (Active "L") is output from the CO pin. This is the normal status.

2. Overcharge status

When the voltage of any of all batteries exceeds the overcharge detection voltage n ($V_{CU n}$) during charging in the normal status and the conditions continue for the overcharge detection delay time (t_{CU}) or longer, the CO pin output inverts. This is the overcharge status. Connecting FET to the CO pin provides charge control and a second protection. When the voltage of all batteries falls below V_{CLn} and the conditions continue for 2.0 ms typ. or longer, the S-8215C Series returns to the normal status.

3. Overcharge timer reset function

During t_{CU} , which is from when the voltage of any of the batteries being charged exceeds $V_{CU n}$ until charging stops, S-8215C Series has the following operations.

Even if an overcharge release noise, which temporarily forces the battery voltage below $V_{CU n}$, is input, t_{CU} is continuously counted as long as the overcharge release noise time is shorter than the overcharge timer reset delay time (t_{TR}). Under the same conditions, if the overcharge release noise time is t_{TR} or longer, counting of t_{CU} is reset once. After that, when $V_{CU n}$ has been exceeded, counting of t_{CU} resumes.

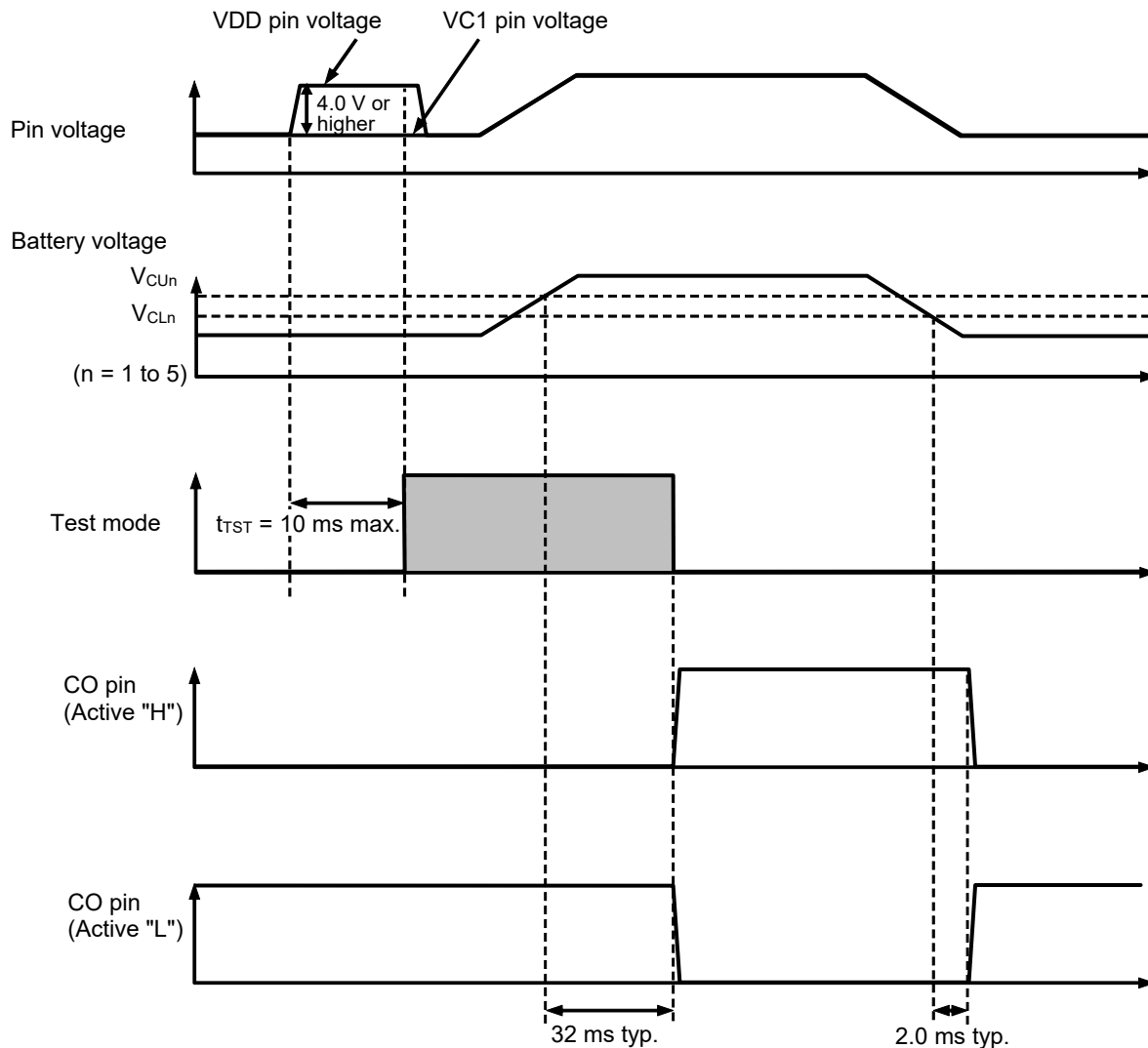
Remark $n = 1$ to 5

4. Test mode

t_{CU} can be shortened by transitioning to the test mode.

S-8215C Series transitions to the test mode by retaining the VDD pin voltage at 4.0 V above the VC1 pin voltage or higher for at least transition time to test mode (t_{TST}). The status is retained by the internal latch and the test mode is retained even if the VDD pin voltage is decreased to the same voltage as that of the VC1 pin voltage.

After that, when S-8215C Series becomes the overcharge status, the test mode retaining latch is reset and the S-8215C Series is released from the test mode.



- Caution**
1. Transition to test mode when the voltage of all batteries is lower than V_{CU_n} .
 2. The overcharge timer reset delay time (t_{TR}) is not shortened in the test mode.

Figure 9

■ Timing Charts

1. Overcharge detection operation

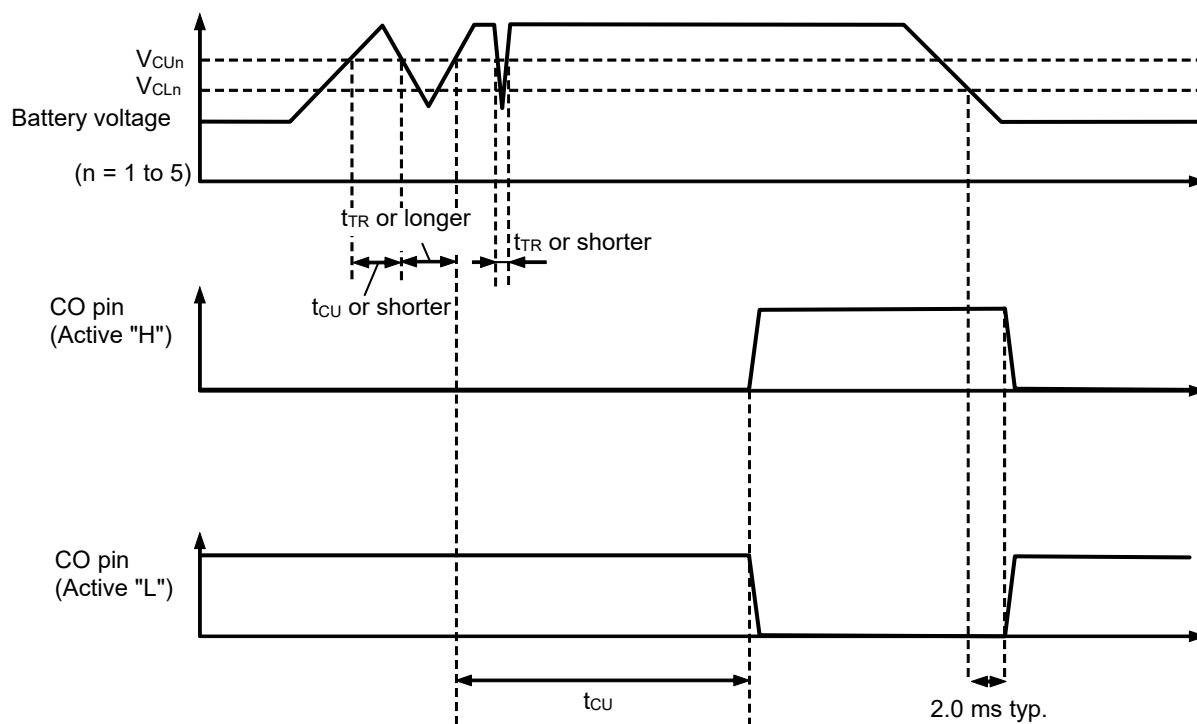


Figure 10

2. Overcharge timer reset function

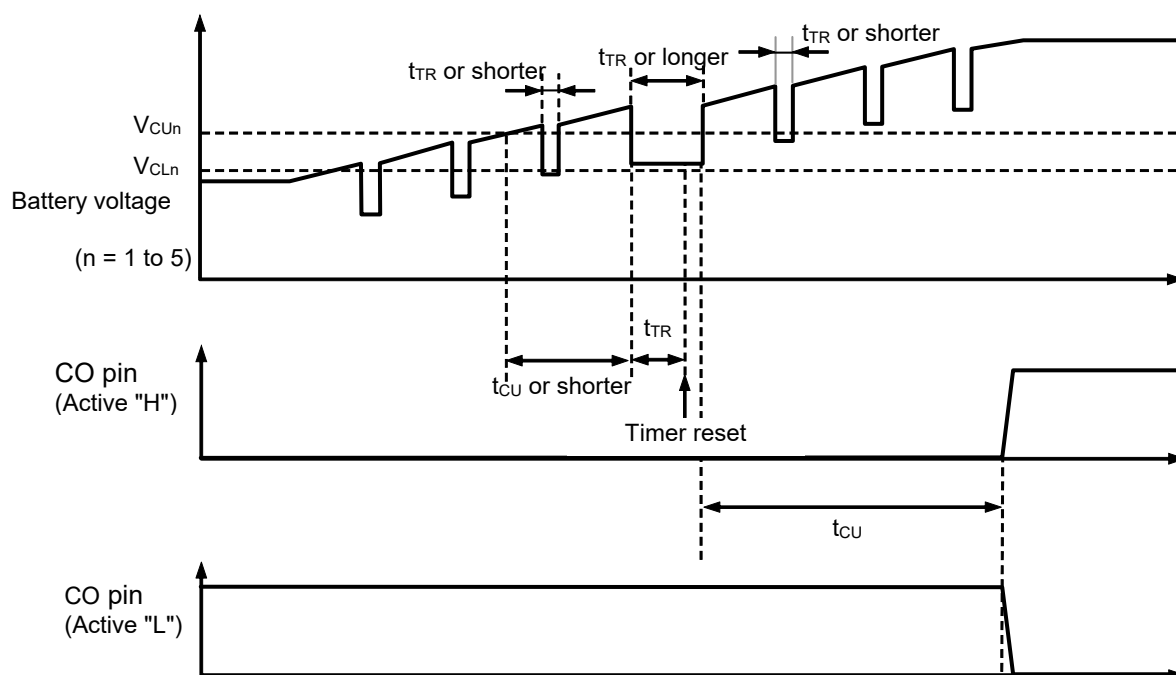


Figure 11

■ Battery Protection IC Connection Examples

1. 5-serial cell (CMOS output product)

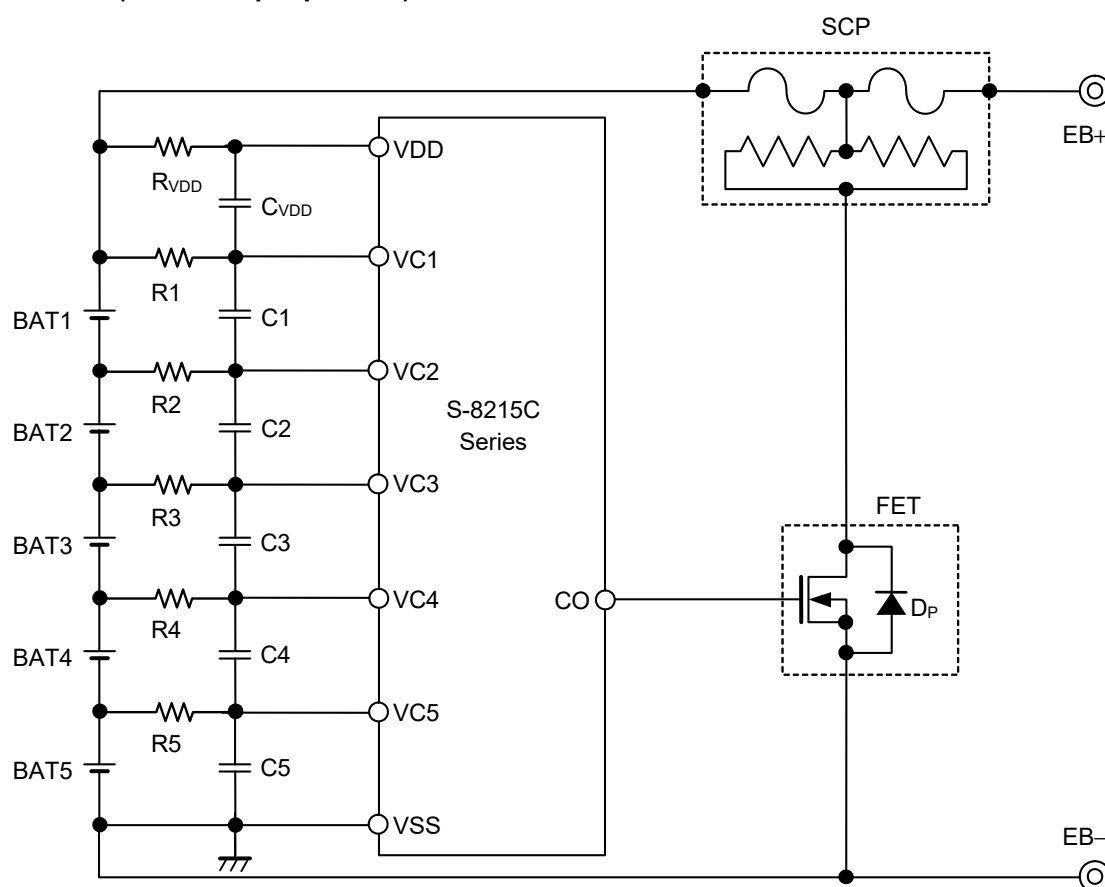


Figure 12

Table 9 Constants for External Components

| No. | Symbol | Min. | Typ. | Max. | Unit |
|-----|----------------------------|------|------|------|---------------|
| 1 | R1 to R5 | 100 | 1000 | 1000 | Ω |
| 2 | C1 to C5, C _{VDD} | 0.1 | 0.1 | 1 | μF |
| 3 | R _{VDD} | 100 | 100 | 1000 | Ω |

- Caution**
1. The constants may be changed without notice.
 2. It has not been confirmed whether the operation is normal or not in circuits other than the connection example. In addition, the connection example and the constants do not guarantee proper operation. Perform thorough evaluation using the actual application to set the constants.
 3. R1 to R5 should be the same constant. C1 to C5 and C_{VDD} should be the same constant.

2. 4-serial cell (CMOS output product)

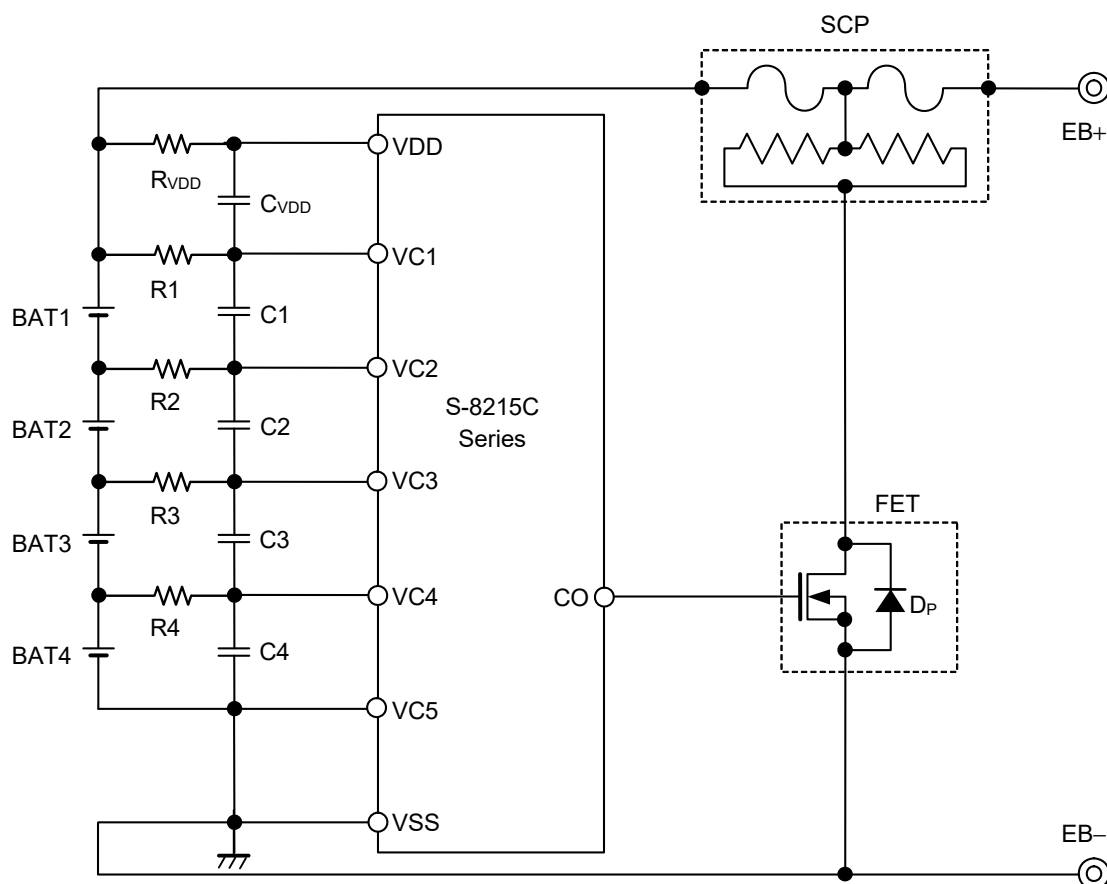


Figure 13

Table 10 Constants for External Components

| No. | Symbol | Min. | Typ. | Max. | Unit |
|-----|---------------------|------|------|------|----------|
| 1 | R1 to R4 | 100 | 1000 | 1000 | Ω |
| 2 | C1 to C4, C_{VDD} | 0.1 | 0.1 | 1 | μF |
| 3 | R_{VDD} | 100 | 100 | 1000 | Ω |

- Caution**
1. The constants may be changed without notice.
 2. It has not been confirmed whether the operation is normal or not in circuits other than the connection example. In addition, the connection example and the constants do not guarantee proper operation. Perform thorough evaluation using the actual application to set the constants.
 3. R1 to R4 should be the same constant. C1 to C4 and C_{VDD} should be the same constant.

3. 3-serial cell (CMOS output product)

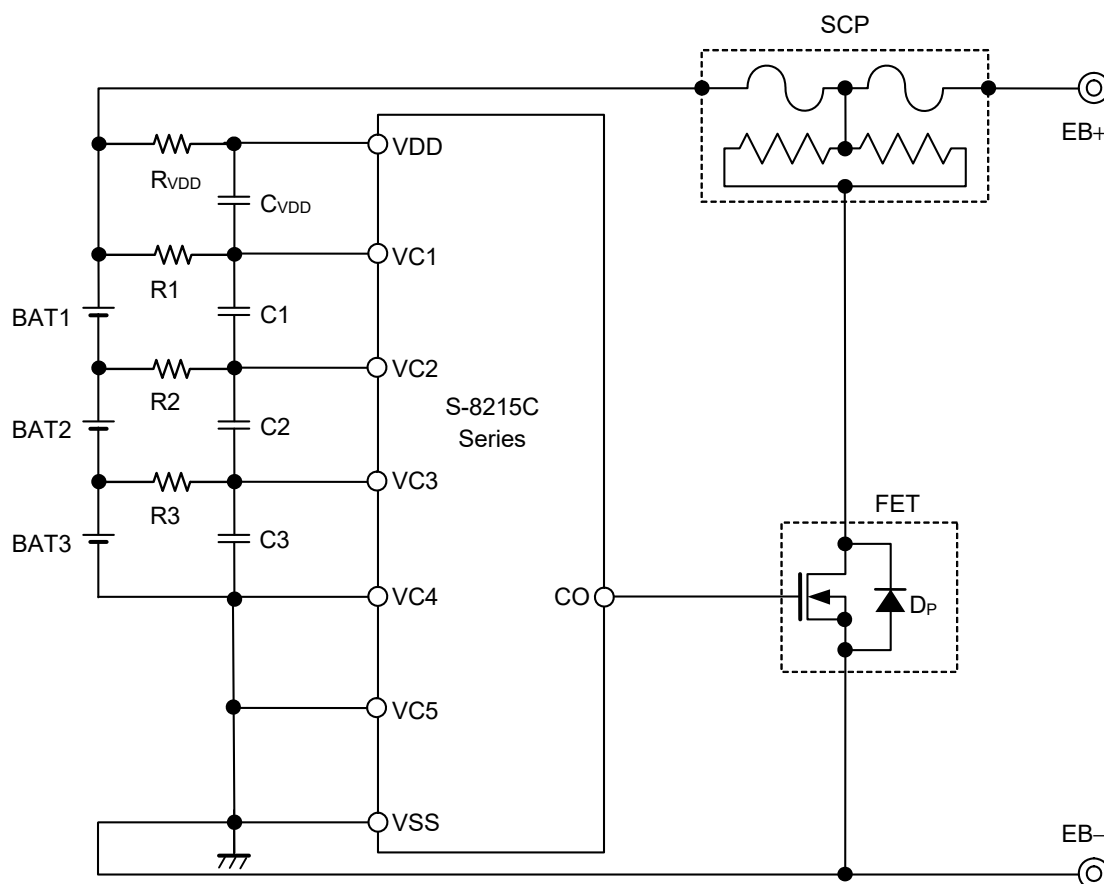


Figure 14

Table 11 Constants for External Components

| No. | Symbol | Min. | Typ. | Max. | Unit |
|-----|---------------------|------|------|------|----------|
| 1 | R1 to R3 | 100 | 1000 | 1000 | Ω |
| 2 | C1 to C3, C_{VDD} | 0.1 | 0.1 | 1 | μF |
| 3 | R_{VDD} | 100 | 100 | 1000 | Ω |

- Caution**
1. The constants may be changed without notice.
 2. It has not been confirmed whether the operation is normal or not in circuits other than the connection example. In addition, the connection example and the constants do not guarantee proper operation. Perform thorough evaluation using the actual application to set the constants.
 3. R1 to R3 should be the same constant. C1 to C3 and C_{VDD} should be the same constant.

[For SCP, contact]

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<https://www.dexerials.jp/en/>

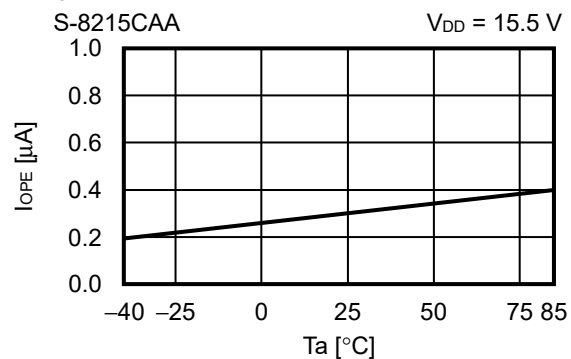
■ Precautions

- Do not connect batteries charged with V_{CLn} or higher. If the connected batteries include a battery charged with V_{CLn} or higher, the S-8215C Series may become overcharge status after all pins are connected.
- In some application circuits, even if an overcharged battery is not included, the order of connecting batteries may be restricted to prevent transient output of CO detection pulses when the batteries are connected. Perform thorough evaluation with the actual application circuit.
- Before the battery connection, short-circuit the battery side pins R_{VDD} and R1, shown in the figure in "**■ Battery Protection IC Connection Examples**".
- The application conditions for the input voltage, output voltage, and load current should not exceed the power dissipation.
- Do not apply to this IC an electrostatic discharge that exceeds the performance ratings of the built-in electrostatic protection circuit.
- ABLIC Inc. claims no responsibility for any disputes arising out of or in connection with any infringement of patents owned by a third party by products including this IC.

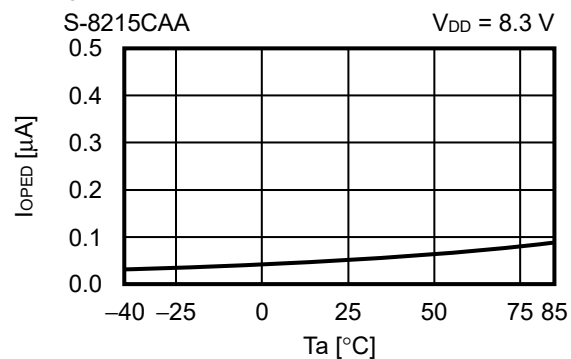
■ Characteristics (Typical Data)

1. Current consumption

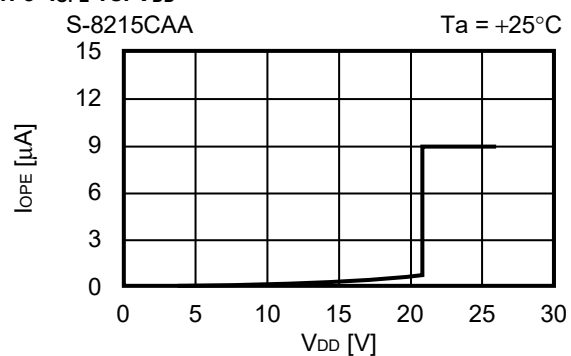
1. 1 I_{OPE} vs. T_a



1. 2 I_{OPED} vs. T_a

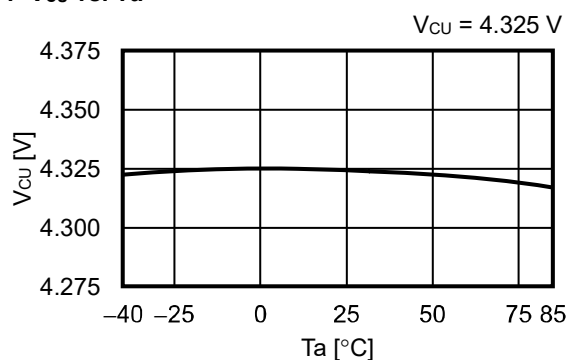


1. 3 I_{OPE} vs. V_{DD}

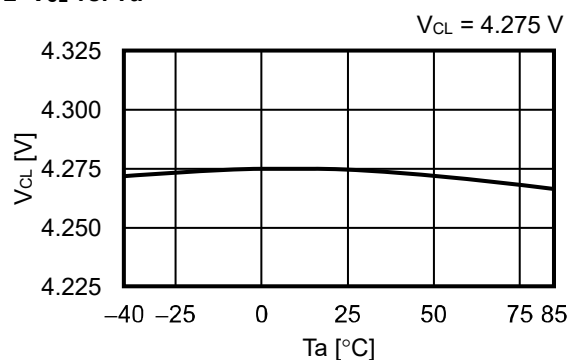


2. Detection voltage

2. 1 V_{CU} vs. T_a

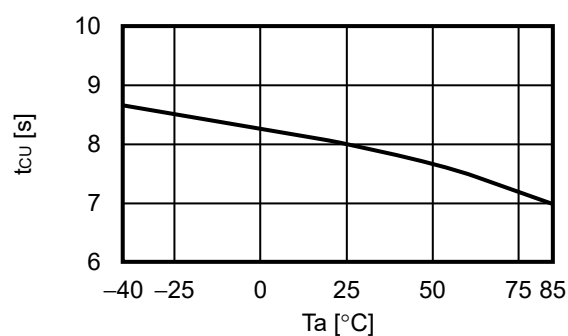


2. 2 V_{CL} vs. T_a



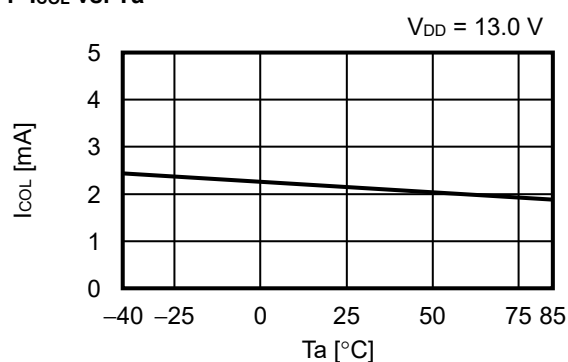
3. Delay time

3. 1 t_{CU} vs. T_a

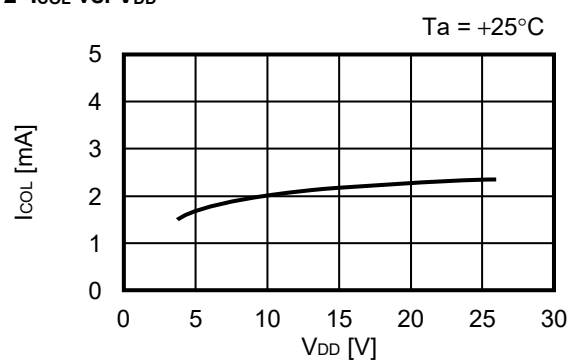


4. Output current

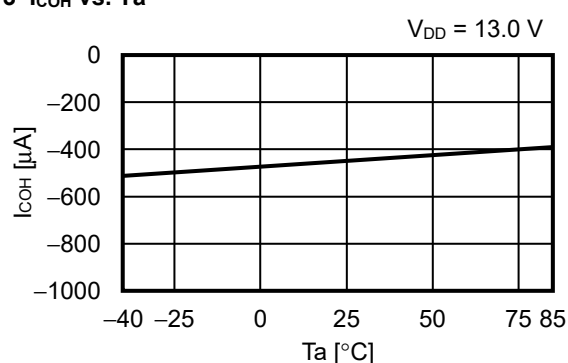
4. 1 I_{COL} vs. T_a



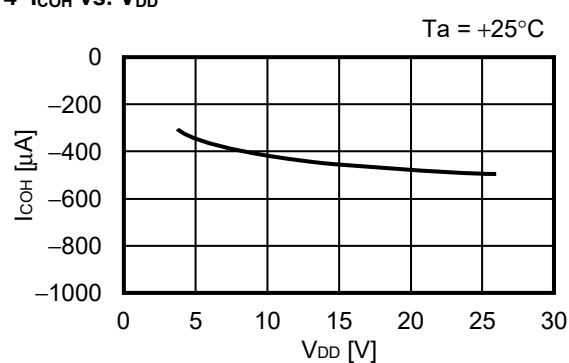
4. 2 I_{COL} vs. V_{DD}



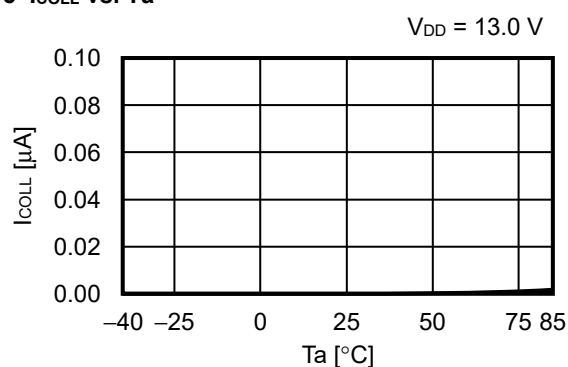
4. 3 I_{COH} vs. T_a



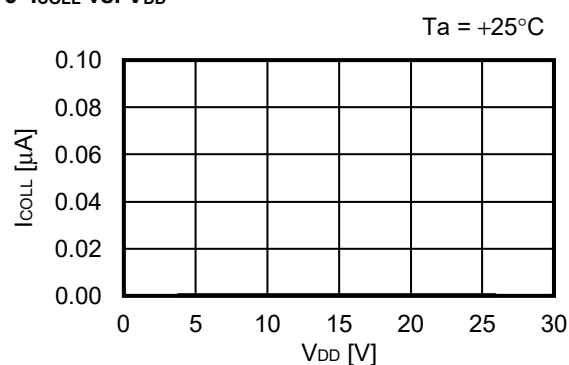
4. 4 I_{COH} vs. V_{DD}



4. 5 I_{COLL} vs. T_a

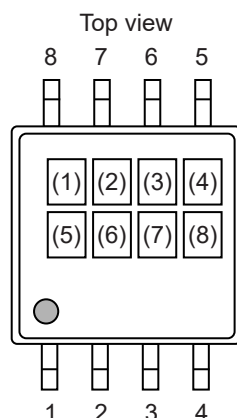


4. 6 I_{COLL} vs. V_{DD}



■ Marking Specifications

1. TMSOP-8

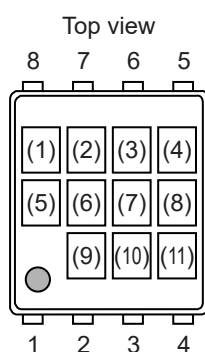


- (1): Blank
- (2) to (4): Product code (Refer to **Product name vs. Product code**)
- (5): Blank
- (6) to (8): Lot number

Product name vs. Product code

| Product Name | Product Code | | |
|------------------|--------------|-----|-----|
| | (2) | (3) | (4) |
| S-8215CAA-K8T2U7 | H | Y | A |
| S-8215CAB-K8T2U7 | H | Y | B |
| S-8215CAC-K8T2U7 | H | Y | C |
| S-8215CAD-K8T2U7 | H | Y | D |
| S-8215CAE-K8T2U7 | H | Y | E |
| S-8215CAF-K8T2U7 | H | Y | F |

2. SNT-8A



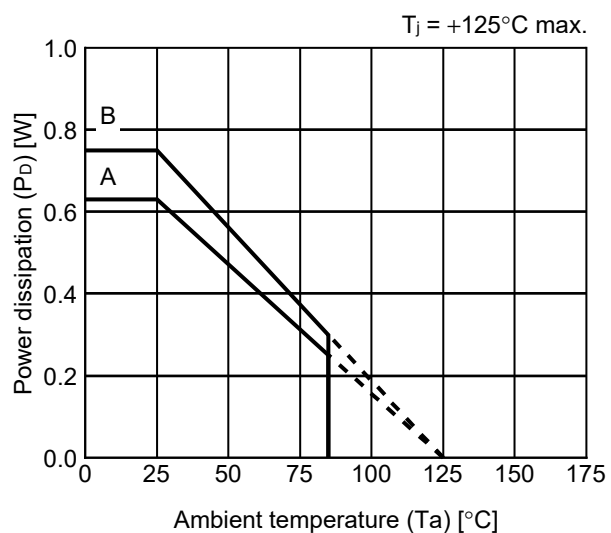
- (1): Blank
- (2) to (4): Product code (Refer to **Product name vs. Product code**)
- (5), (6): Blank
- (7) to (11): Lot number

Product name vs. Product code

| Product Name | Product Code | | |
|------------------|--------------|-----|-----|
| | (2) | (3) | (2) |
| S-8215CAA-I8T1U7 | H | Y | A |

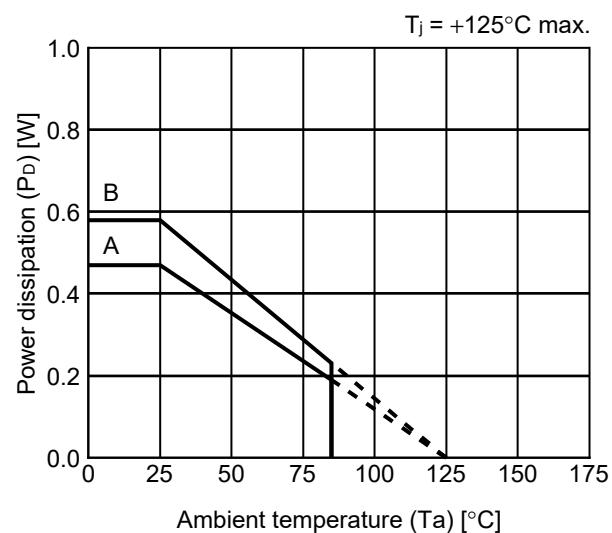
■ Power Dissipation

TMSOP-8



| Board | Power Dissipation (P_D) |
|-------|-----------------------------|
| A | 0.63 W |
| B | 0.75 W |
| C | — |
| D | — |
| E | — |

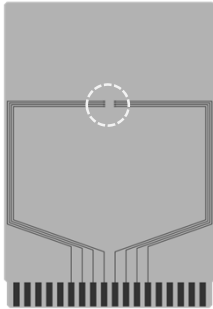
SNT-8A




| Board | Power Dissipation (P_D) |
|-------|-----------------------------|
| A | 0.47 W |
| B | 0.58 W |
| C | — |
| D | — |
| E | — |

TMSOP-8 Test Board

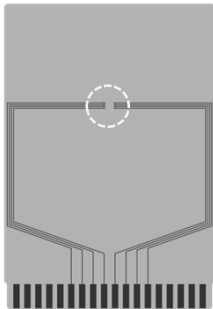
(1) Board A



 IC Mount Area

| Item | | Specification |
|-----------------------------|---|---|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 2 |
| Copper foil layer [mm] | 1 | Land pattern and wiring for testing: t0.070 |
| | 2 | - |
| | 3 | - |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | - |

(2) Board B

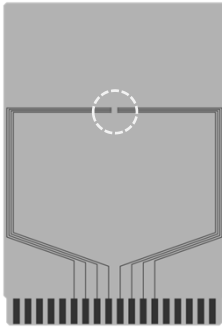


| Item | | Specification |
|-----------------------------|---|---|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 4 |
| Copper foil layer [mm] | 1 | Land pattern and wiring for testing: t0.070 |
| | 2 | 74.2 x 74.2 x t0.035 |
| | 3 | 74.2 x 74.2 x t0.035 |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | - |

No. TMSOP8-A-Board-SD-1.0

SNT-8A Test Board

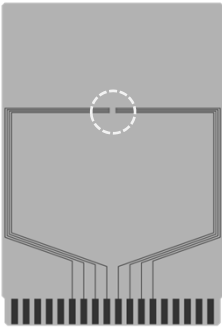
(1) Board A



 IC Mount Area

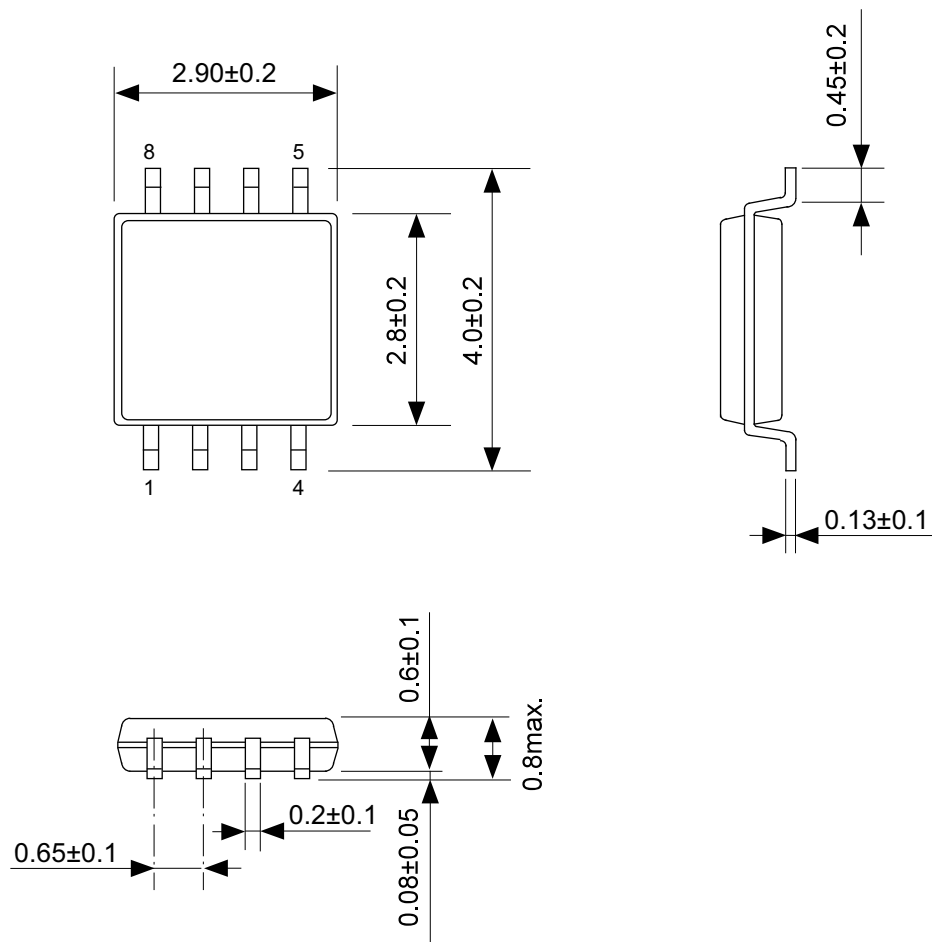
| Item | | Specification |
|-----------------------------|---|---|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 2 |
| Copper foil layer [mm] | 1 | Land pattern and wiring for testing: t0.070 |
| | 2 | - |
| | 3 | - |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | - |

(2) Board B




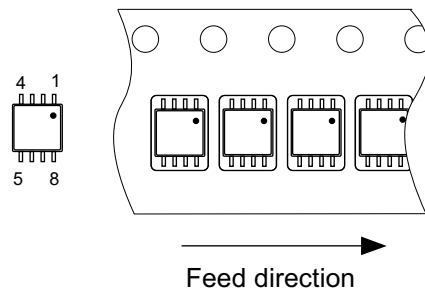
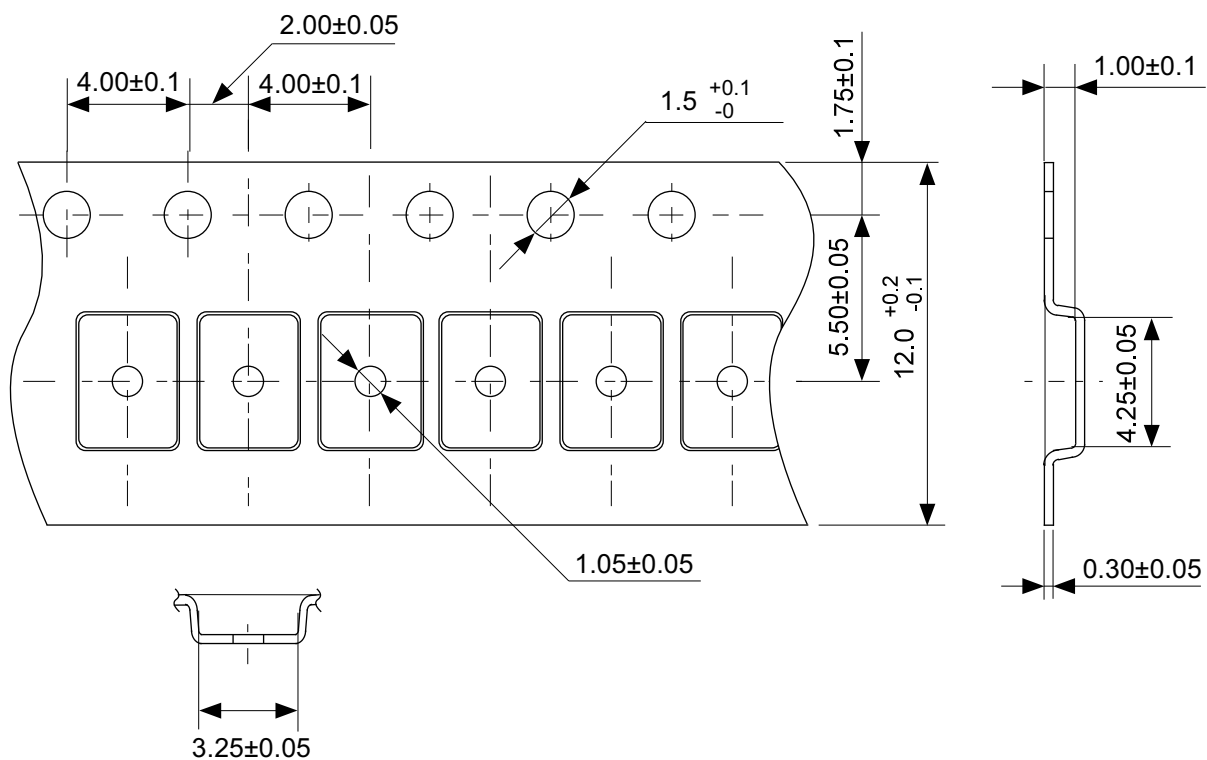
| Item | | Specification |
|-----------------------------|---|---|
| Size [mm] | | 114.3 x 76.2 x t1.6 |
| Material | | FR-4 |
| Number of copper foil layer | | 4 |
| Copper foil layer [mm] | 1 | Land pattern and wiring for testing: t0.070 |
| | 2 | 74.2 x 74.2 x t0.035 |
| | 3 | 74.2 x 74.2 x t0.035 |
| | 4 | 74.2 x 74.2 x t0.070 |
| Thermal via | | - |

No. SNT8A-A-Board-SD-1.0



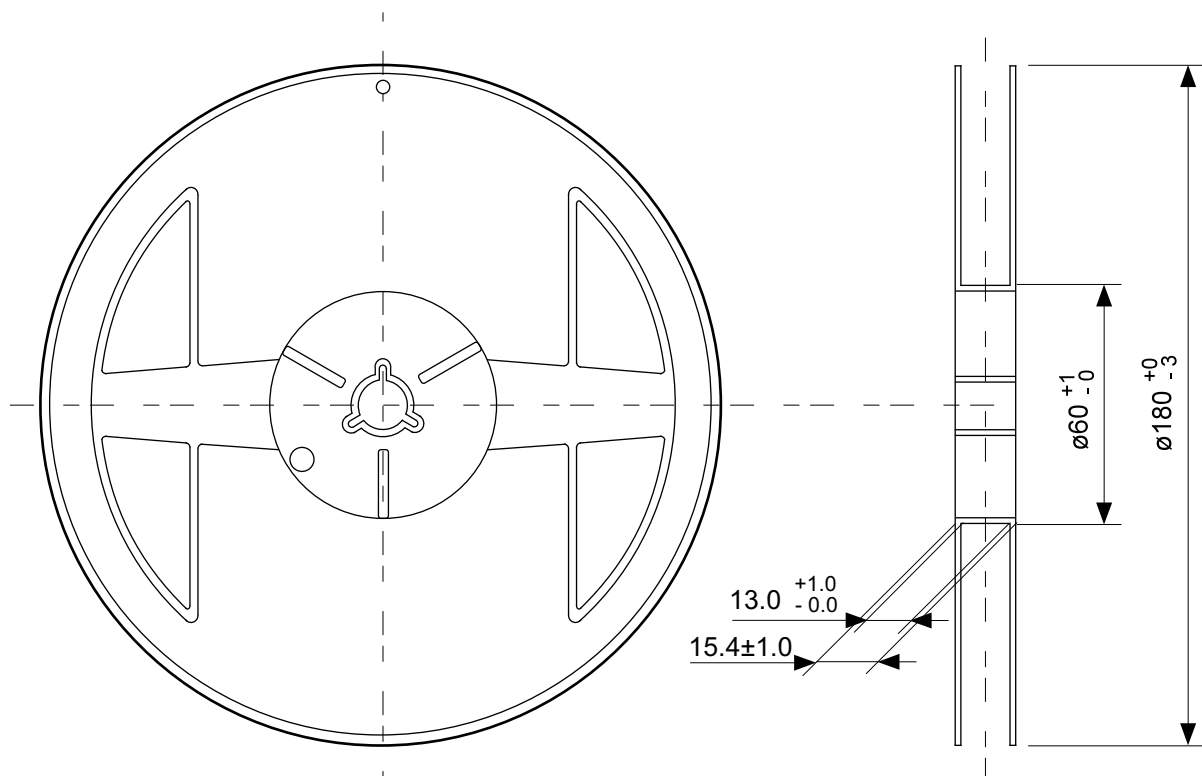
No. FM008-A-P-SD-1.2

| | |
|------------|---|
| TITLE | TMSOP8-A-PKG Dimensions |
| No. | FM008-A-P-SD-1.2 |
| ANGLE |  |
| UNIT | mm |
| | |
| ABLIC Inc. | |

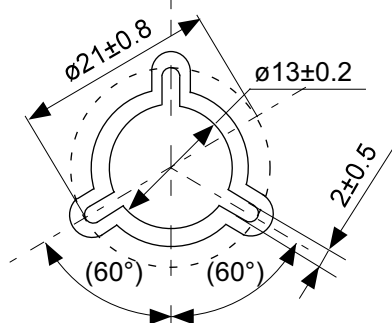


No. FM008-A-C-SD-2.0

| | |
|------------|-----------------------|
| TITLE | TMSOP8-A-Carrier Tape |
| No. | FM008-A-C-SD-2.0 |
| ANGLE | |
| UNIT | mm |
| | |
| ABLIC Inc. | |

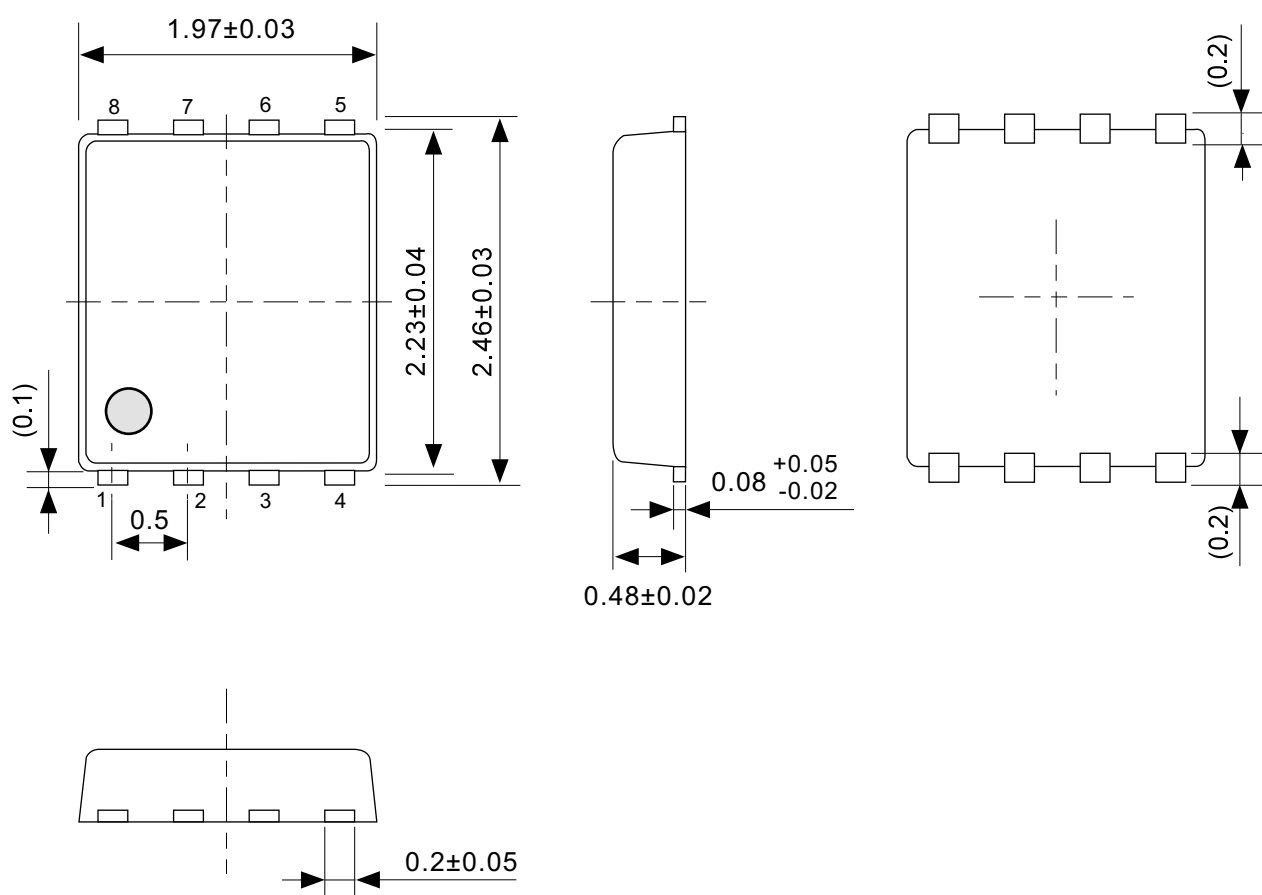


Enlarged drawing in the central part




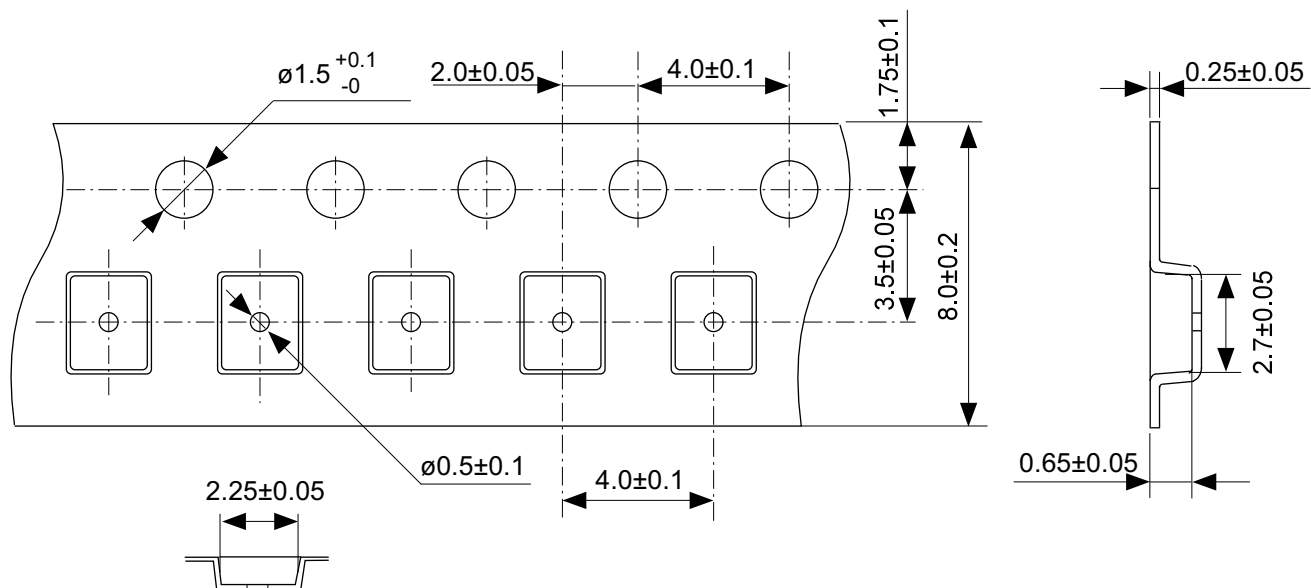
No. FM008-A-R-SD-2.0

| | | | |
|------------|------------------|------|-------|
| TITLE | TMSOP8-A-Reel | | |
| No. | FM008-A-R-SD-2.0 | | |
| ANGLE | | QTY. | 4,000 |
| UNIT | mm | | |
| | | | |
| ABLIC Inc. | | | |

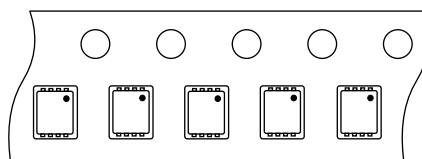


No. PH008-A-P-SD-2.1

| | |
|------------|---|
| TITLE | SNT-8A-A-PKG Dimensions |
| No. | PH008-A-P-SD-2.1 |
| ANGLE |  |
| UNIT | mm |
| | |
| ABLIC Inc. | |



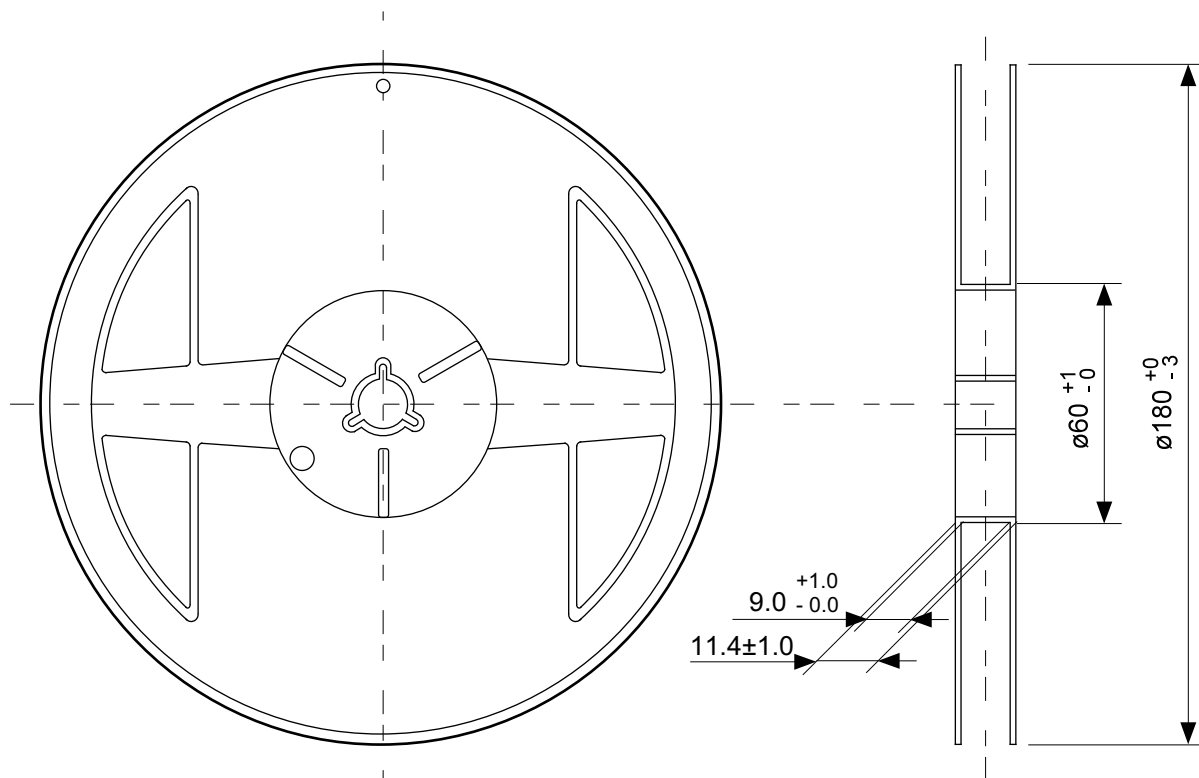
4 3 2 1
5 6 7 8



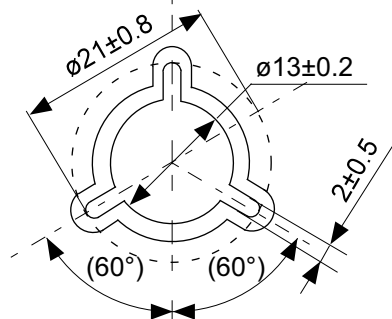
Feed direction

No. PH008-A-C-SD-2.0

| | |
|------------|-----------------------|
| TITLE | SNT-8A-A-Carrier Tape |
| No. | PH008-A-C-SD-2.0 |
| ANGLE | |
| UNIT | mm |
| | |
| ABLIC Inc. | |

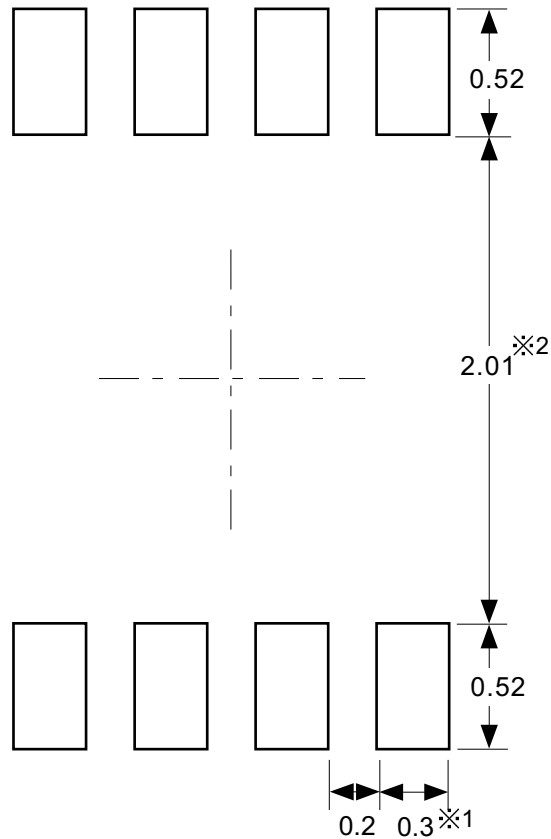


Enlarged drawing in the central part



No. PH008-A-R-SD-2.0

| | | | |
|------------|------------------|------|-------|
| TITLE | SNT-8A-A-Reel | | |
| No. | PH008-A-R-SD-2.0 | | |
| ANGLE | | QTY. | 5,000 |
| UNIT | mm | | |
| | | | |
| ABLIC Inc. | | | |



※1. ランドパターンの幅に注意してください (0.25 mm min. / 0.30 mm typ.).

※2. パッケージ中央にランドパターンを広げないでください (1.96 mm ~ 2.06 mm)。

- 注意
1. パッケージのモールド樹脂下にシルク印刷やハンダ印刷などしないでください。
 2. パッケージ下の配線上のソルダーレジストなどの厚みをランドパターン表面から0.03 mm以下にしてください。
 3. マスク開口サイズと開口位置はランドパターンと合わせてください。
 4. 詳細は“SNTパッケージ活用の手引き”を参照してください。

※1. Pay attention to the land pattern width (0.25 mm min. / 0.30 mm typ.).

※2. Do not widen the land pattern to the center of the package (1.96 mm to 2.06mm).

- Caution**
1. Do not do silkscreen printing and solder printing under the mold resin of the package.
 2. The thickness of the solder resist on the wire pattern under the package should be 0.03 mm or less from the land pattern surface.
 3. Match the mask aperture size and aperture position with the land pattern.
 4. Refer to "SNT Package User's Guide" for details.

※1. 请注意焊盘模式的宽度 (0.25 mm min. / 0.30 mm typ.).

※2. 请勿向封装中间扩展焊盘模式 (1.96 mm ~ 2.06 mm)。

- 注意
1. 请勿在树脂型封装的下面印刷丝网、焊锡。
 2. 在封装下、布线上的阻焊膜厚度 (从焊盘模式表面起) 请控制在 0.03 mm 以下。
 3. 钢网的开口尺寸和开口位置请与焊盘模式对齐。
 4. 详细内容请参阅 "SNT 封装的应用指南"。

No. PH008-A-L-SD-4.1

| | |
|------------|----------------------------------|
| TITLE | SNT-8A-A -Land Recommendation |
| No. | PH008-A-L-SD-4.1 |
| ANGLE | |
| UNIT | mm |
| | |
| ABLIC Inc. | |

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